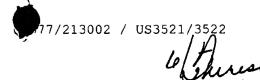
Attorney's Docket No.:



THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant :

Ohtani, et al.

Art Unit: 28

2815

Serial No.:

09/455,991

Examiner:

Jose R. Diaz

Filed

December 6, 1999

Title :

SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING

THE SAME

Commissioner for Patents Washington, D.C. 20231

RESPONSE

In response to the action mailed November 21, 2000, please amend the application as follows:

In the claims:

Please amend claims 6-12 as follows:

6. (Amended) A method of manufacturing a semiconductor

device, said method comprising:

forming an amorphous semiconductor film on an

insulating surface;

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR \$1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

	April 23, 2001	
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